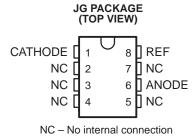
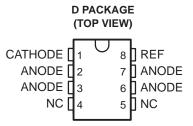
- 0.4% Initial Voltage Tolerance
- **0.2-**Ω Typical Output Impedance
- Fast Turnon . . . 500 ns
- Sink Current Capability . . . 1 mA to 100 mA
- Low Reference Current (REF)
- Adjustable Output Voltage . . . V_{I(ref)} to 36 V

description

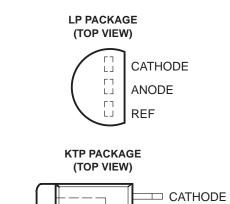
The TL1431 is a precision programmable reference with specified thermal stability over automotive. commercial, and temperature ranges. The output voltage can be set to any value between V_{I(ref)} (approximately 2.5 V) and 36 V with two external resistors (see Figure 16). This device has a typical output impedance of 0.2Ω . Active output circuitry provides a very sharp turnon characteristic, making the device an excellent replacement for zener diodes and other types of references in applications such as onboard regulation, adjustable power supplies, and switching power supplies.

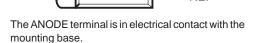
The TL1431C is characterized for operation over the commercial temperature range of 0°C to 70°C. The TL1431Q is characterized for operation over the full automotive temperature range of -40°C to 125°C. The TL1431M is characterized for operation over the full military temperature range of -55°C to 125°C.





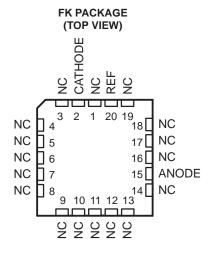
NC - No internal connection ANODE terminals are connected internally.





ANODE □ REF

ANODE





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



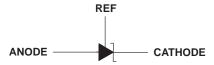
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AVAILABLE OPTIONS

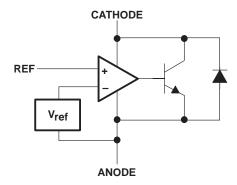
	PACKAGED DEVICES						
TA	SMALL OUTLINE (D)	PLASTIC FLANGE MOUNTED (KTP)	TO-226AA (LP)	CHIP CARRIER (FK)	CERAMIC DIP (JG)	CHIP FORM (Y)	
0°C to 70°C	TL1431CD	TL1431CKTPR	TL1431CLP	-	-		
-40°C to 125°C	TL1431QD	-	TL1431QLP	-	-	TL1431Y	
−55°C to 125°C	-	_	_	TL1431MFK	TL1431MJG		

The D and LP packages are available taped and reeled. The KTP package is only available taped and reeled. Add the suffix R to the device type (e.g., TL1431CDR). Chip forms are tested at 25°C.

logic symbol

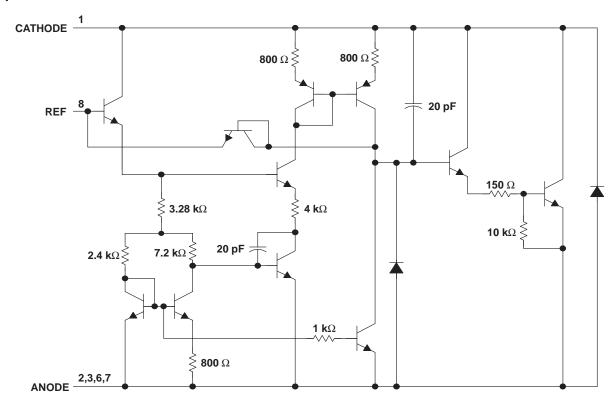


functional block diagram





equivalent schematic†



† All component values are nominal. Pin numbers shown are for the D package.

SLVS062F - DECEMBER 1991 - REVISED JANUARY 2000

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Cathode voltage, V _{KA} (see Note 1)		37 V
Continuous cathode current range, I _{KA}		
Reference input current range, I _{I(ref)}		–50 μA to 10 mA
Package thermal impedance, θ_{JA} (see Notes 2 and 3):	D package	97°C/W
, 0 /(·	KTP package	28°C/W
	LP package	156°C/W
Lead temperature 1,6 mm (1/16 inch) from case for 10	seconds	260°C
Storage temperature range, T _{sto}		

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values are with respect to ANODE unless otherwise noted.
 - 2. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can impact reliability.
 - 3. The package thermal impedance is calculated in accordance with JESD 51.

POWER DISSIPATION RATING TABLE - FREE-AIR TEMPERATURE

PACKAGE	T _A = 25°C POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING	T _A = 125°C POWER RATING
FK	1375 mW	11.0 mW/°C	880 mW	715 mW	275 mW
JG	1050 mW	8.4 mW/°C	672 mW	546 mW	210 mW

recommended operating conditions

			MIN	MAX	UNIT
VKA	V _{KA} Cathode voltage			36	V
IKA	Cathode current		1	100	mA
		TL1431C	0	70	
TA	Operating free-air temperature	TL1431Q	-40	125	°C
		TL1431M	-55	125	



electrical characteristics at specified free-air temperature, $I_{KA} = 10 \text{ mA}$ (unless otherwise noted)

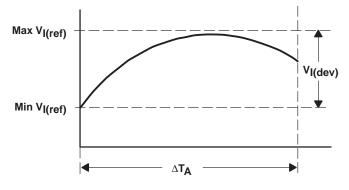
PARAMETER		TEST CONDITIO	MC	. .+	TEST	TL1431C			UNIT
	PARAMETER	TEST CONDITIO	ONS	T _A †	CIRCUIT	MIN	TYP	MAX	ONII
	Reference			25°C		2490	2500	2510	
V _{I(ref)}	input voltage	$V_{KA} = V_{I(ref)}$		Full range	Figure 1	2480		2520	mV
V _{I(dev)}	Deviation of reference input voltage over full temperature range‡	$V_{KA} = V_{I(ref)}$		Full range	Figure 1		4	20	mV
$\frac{\Delta V_{I(ref)}}{\Delta V_{KA}}$	Ratio of change in reference input voltage to the change in cathode voltage	ΔV _{KA} = 3 V to 36 V		Full range	Figure 2		-1.1	-2	mV/V
	Reference			25°C			1.5	2.5	
I _{I(ref)}	input current	$R1 = 10 \text{ k}\Omega,$	R2 = ∞	Full range	Figure 2			3	μΑ
I _{I(dev)}	Deviation of reference input current over full temperature range‡	R1 = 10 kΩ,	R2 = ∞	Full range	Figure 2		0.2	1.2	μΑ
	Minimum cathode current for regulation	$V_{KA} = V_{I(ref)}$ to 36 V		25°C	Figure 1		0.45	1	mA
	Off-state			25°C			0.18	0.5	
l _{off}	cathode current	V _{KA} = 36 V,	$V_{I(ref)} = 0$	Full range	Figure 3			2	μА
Izkal	Output impedance§	$V_{KA} = V_{I(ref)}$, $f \le 1$ kHz, $I_{KA} = 1$ mA to 100 mA		25°C	Figure 1		0.2	0.4	Ω

[†] Full range is 0°C to 70°C for C-suffix devices.

$$\left|\alpha_{V_{\mbox{\footnotesize I(ref)}}}\!\!\left|\!\left(\!\frac{\mbox{\footnotesize ppm}}{^{\circ}\mbox{\footnotesize C}}\!\right)\right. = \frac{\left(\!\frac{V_{\mbox{\footnotesize I(dev)}}}{V_{\mbox{\footnotesize I(ref)}}\mbox{\footnotesize at 25°C}}\!\right) \times 10^{6}}{\Delta T_{\mbox{\footnotesize A}}}\right.$$

where:

 $\Delta T_{\mbox{\scriptsize A}}$ is the rated operating temperature range of the device.



 $\alpha_{V_{l(ref)}}$ is positive or negative depending on whether minimum $V_{l(ref)}$ or maximum $V_{l(ref)}$, respectively, occurs at the lower temperature.

§ The output impedance is defined as: $|z_{KA}| = \frac{\Delta V_{KA}}{\Delta I_{KA}}$

When the device is operating with two external resistors (see Figure 2), the total dynamic impedance of the circuit is given by: $|z'| = \frac{\Delta V}{\Delta I}$, which is approximately equal to $|z_{KA}| \left(1 + \frac{R1}{R2}\right)$.

[‡] The deviation parameters V_{I(dev)} and I_{I(dev)} are defined as the differences between the maximum and minimum values obtained over the rated temperature range. The average full-range temperature coefficient of the reference input voltage α_{V_{I(ref)}} is defined as:

electrical characteristics at specified free-air temperature, I_{KA} = 10 mA (unless otherwise noted)

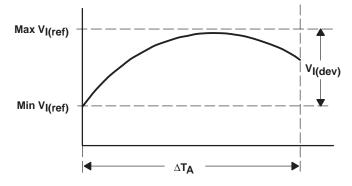
	ARAMETER	TEST CONDITIONS	- +	TEST	Т	L1431Q		Т	L1431M		mV mV/V μA μA
	ARAWEIER	TEST CONDITIONS	T _A †	CIRCUIT	MIN	TYP	MAX	MIN	TYP	MAX	
V _{I(ref)}	Reference input voltage	$V_{KA} = V_{I(ref)}$	25°C Full	Figure 1	2490 2470	2500	2510 2530	2475 2460	2500	2540 2550	mV
V _I (dev)	Deviation of reference input voltage over full temperature range‡	VKA = VI(ref)	Full range	Figure 1		17	55		17	55*	mV
$\frac{\Delta V_{I(ref)}}{\Delta V_{KA}}$	Ratio of change in reference input voltage to the change in cathode voltage	$\Delta V_{KA} = 3 \text{ V to } 36 \text{ V}$	Full range	Figure 2		-1.1	-2		-1.1	-2	mV/V
	Reference		25°C			1.5	2.5		1.5	2.5	
I _{I(ref)}	input current	R1 = 10 k Ω , R2 = ∞	Full range	Figure 2			4			5	μΑ
I(dev)	Deviation of reference input current over full temperature range‡	R1 = 10 kΩ, R2 = ∞	Full range	Figure 2		0.5	2		0.5	3*	μΑ
	Minimum cathode current for regulation	V _{KA} = V _{I(ref)} to 36 V	25°C	Figure 1		0.45	1		0.45	1	mA
	Off-state		25°C			0.18	0.5		0.18	0.5	
l _{off}	cathode current	$V_{KA} = 36 \text{ V}, V_{I(ref)} = 0$	Full range	Figure 3			2			2	μΑ
IzKAI	Output impedance§	$V_{KA} = V_{I(ref)}$, $f \le 1$ kHz, $I_{KA} = 1$ mA to 100 mA	25°C	Figure 1		0.2	0.4		0.2	0.4	Ω

^{*}On products compliant to MIL-PRF-38535, this parameter is not production tested.

$$\left|\alpha_{V_{\mbox{\footnotesize I(ref)}}}\right|\!\!\left(\!\frac{\mbox{\footnotesize ppm}}{^{\circ}\mbox{\footnotesize C}}\!\right) = \frac{\left(\!\frac{V_{\mbox{\footnotesize I(dev)}}}{V_{\mbox{\footnotesize I(ref)}}\,\mbox{\footnotesize at }25^{\circ}\mbox{\footnotesize C}}\!\right) \times 10^{6}}{\Delta T_{\mbox{\footnotesize A}}}$$

where:

 $\Delta T_{\mbox{\scriptsize A}}$ is the rated operating temperature range of the device.



 $\alpha_{V_{I(ref)}} \text{ is positive or negative depending on whether minimum } V_{I(ref)} \text{ or maximum } V_{I(ref)}, \text{ respectively, occurs at the lower temperature.}$

§ The output impedance is defined as: $\left|z_{KA}\right| = \frac{\Delta V_{KA}}{\Delta I_{KA}}$

When the device is operating with two external resistors (see Figure 2), the total dynamic impedance of the circuit is given by: $|z'| = \frac{\Delta V}{\Delta I}$, which is approximately equal to $|z_{KA}| \left(1 + \frac{R1}{R2}\right)$.



[†] Full range is –40°C to 125°C for Q-suffix devices, and –55°C to 125°C for M-suffix devices.

[‡] The deviation parameters V_{I(dev)} and I_{I(dev)} are defined as the differences between the maximum and minimum values obtained over the rated temperature range. The average full-range temperature coefficient of the reference input voltage α_{V_{I(ref)}} is defined as:

electrical characteristics at I_{KA} = 10 mA, T_A = 25°C

PARAMETER		TEST CONDITIONS	TEST	TL1431Y			LINUT
		TEST CONDITIONS	CIRCUIT	MIN	TYP	MAX	UNIT
V _{I(ref)}	Reference input voltage	V _K A = V _I (ref)	Figure 1	2490	2500	2510	mV
$\frac{\Delta V_{l(ref)}}{\Delta V_{KA}}$	Ratio of change in reference input voltage to the change in cathode voltage	$\Delta V_{KA} = 3 \text{ V to } 36 \text{ V}$	Figure 2		-1.1	-2	mV/V
I _I (ref)	Reference input current	R1 = 10 k Ω , R2 = ∞	Figure 2		1.44	2.5	μΑ
IKAmin	Minimum cathode current for regulation	$V_{KA} = V_{I(ref)}$ to 36 V	Figure 1		0.45	1	mA
I _{off}	Off-state cathode current	$V_{KA} = 36 \text{ V}, \qquad V_{ref} = 0$	Figure 3		0.18	0.5	μΑ
z _K A	Output impedance†	$V_{KA} = V_{I(ref)}$, $f \le 1$ kHz, $I_{KA} = 1$ mA to 100 mA	Figure 1		0.2	0.4	Ω

[†] The output impedance is defined as: $|z'| = \frac{\Delta V}{\Delta l}$

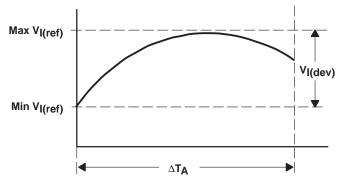
When the device is operating with two external resistors (see Figure 2), the total dynamic impedance of the circuit is given by: $|z_{KA}| = \frac{\Delta V_{KA}}{\Delta I_{KA}}$, which is approximately equal to $|z_{KA}| \left(1 + \frac{R1}{R2}\right)$.

PARAMETER MEASUREMENT INFORMATION

$$\left|\alpha_{V_{I(ref)}}\right|\left(\frac{ppm}{{}^{\circ}C}\right) = \frac{\left(\frac{V_{I(dev)}}{V_{I(ref)} \text{ at } 25{}^{\circ}C}\right) \times 10^{6}}{\Delta T_{A}}$$

where:

 ΔT_A is the rated operating temperature range of the device.



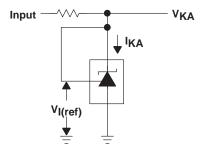


Figure 1. Test Circuit for $V_{(KA)} = V_{ref}$

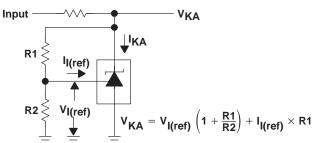


Figure 2. Test Circuit for $V_{(KA)} > V_{ref}$

PARAMETER MEASUREMENT INFORMATION

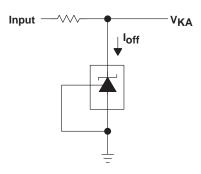


Figure 3. Test Circuit for I_{off}

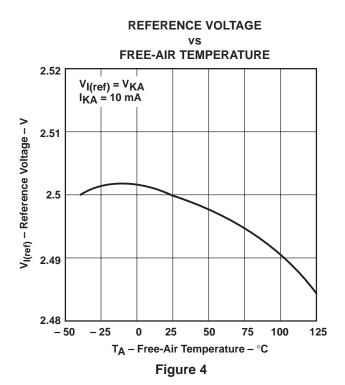
TYPICAL CHARACTERISTICS

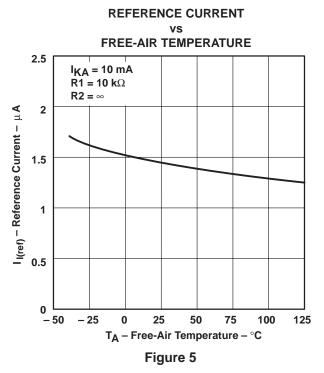
Table of Graphs

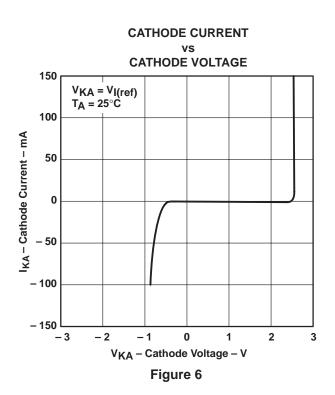
	FIGURE
Reference voltage vs Free-air temperature	4
Reference current vs Free-air temperature	5
Cathode current vs Cathode voltage	6, 7
Off-state cathode current vs Free-air temperature	8
Ratio of delta reference voltage to delta cathode voltage vs Free-air temperature	9
Equivalent input-noise voltage vs Frequency	10
Equivalent input-noise voltage over a 10-second period	11
Small-signal voltage amplification vs Frequency	12
Reference impedance vs Frequency	13
Pulse response	14
Stability boundary conditions	15

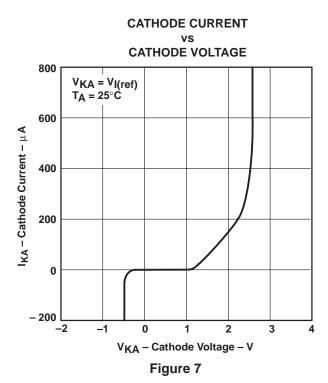


TYPICAL CHARACTERISTICS[†]





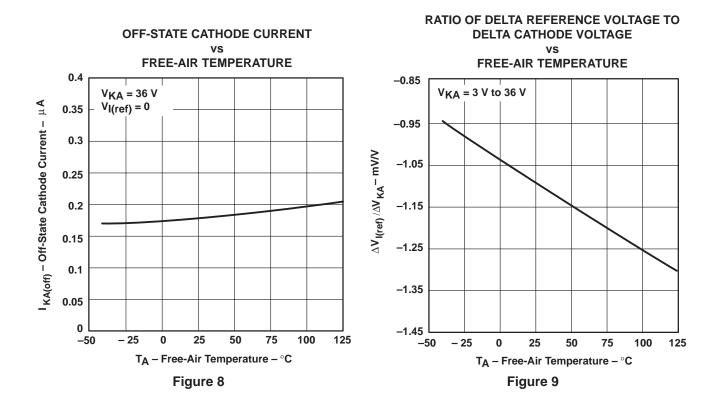




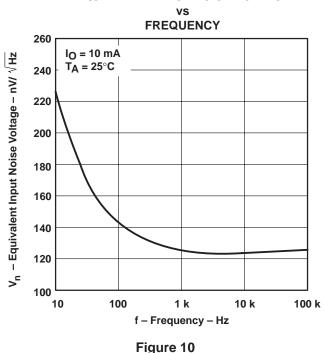
[†] Data at high and low temperatures are applicable only within the recommended operating free-air temperature ranges of the various devices.



TYPICAL CHARACTERISTICS[†]



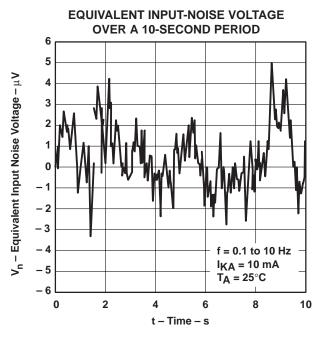
EQUIVALENT INPUT-NOISE VOLTAGE

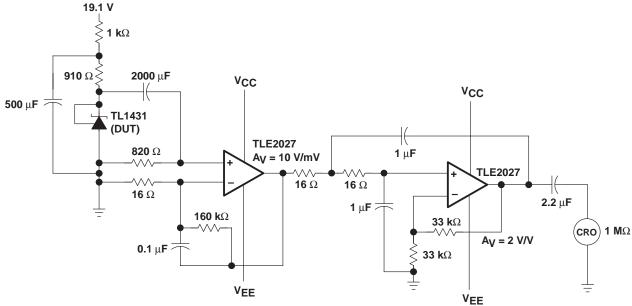


[†] Data at high and low temperatures are applicable only within the recommended operating free-air temperature ranges of the various devices.



TYPICAL CHARACTERISTICS



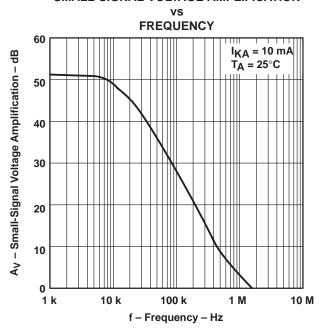


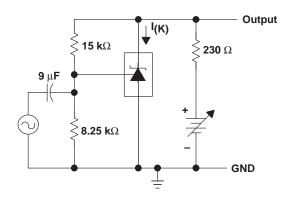
TEST CIRCUIT FOR 0.1-Hz TO 10-Hz EQUIVALENT INPUT-NOISE VOLTAGE

Figure 11

TYPICAL CHARACTERISTICS

SMALL-SIGNAL VOLTAGE AMPLIFICATION

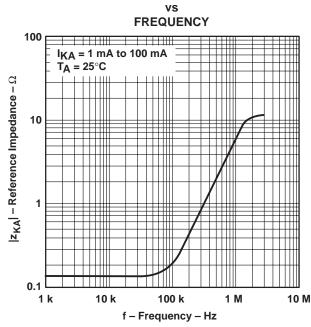


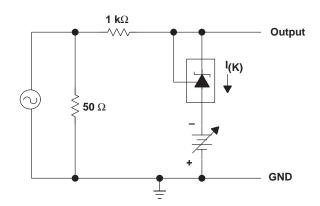


TEST CIRCUIT FOR VOLTAGE AMPLIFICATION

Figure 12

REFERENCE IMPEDANCE



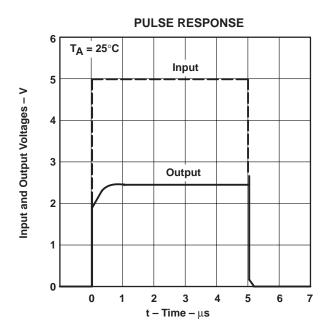


TEST CIRCUIT FOR REFERENCE IMPEDANCE

Figure 13



TYPICAL CHARACTERISTICS



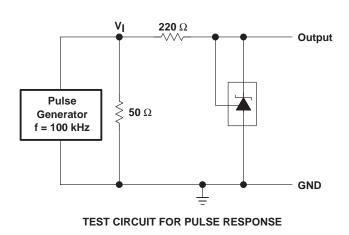
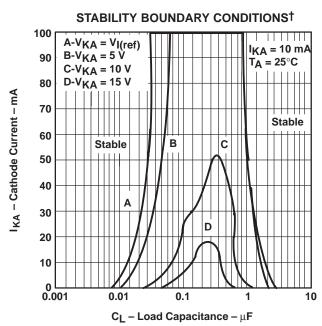
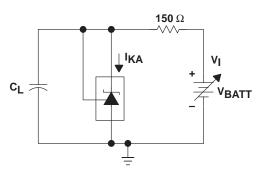


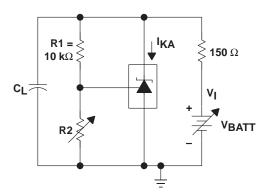
Figure 14



 † The areas under the curves represent conditions that may cause the device to oscillate. For curves B, C, and D, R2 and V+ are adjusted to establish the initial V_{KA} and I_{KA} conditions with C_L = 0. V_{BATT} and C_L are then adjusted to determine the ranges of stability.



TEST CIRCUIT FOR CURVE A



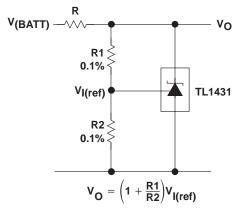
TEST CIRCUIT FOR CURVES B, C, AND D

Figure 15



Table of Application Circuits

APPLICATION	FIGURE
Shunt regulator	16
Single-supply comparator with temperature-compensated threshold	17
Precision high-current series regulator	18
Output control of a three-terminal fixed regulator	19
Higher-current shunt regulator	20
Crowbar	21
Precision 5-V, 1.5-A, 0.5% regulator	22
5-V precision regulator	23
PWM converter with 0.5% reference	24
Voltage monitor	25
Delay timer	26
Precision current limiter	27
Precision constant-current sink	28



NOTE A: R should provide cathode current \geq 1 mA to the TL1431 at minimum V(BATT).

Figure 16. Shunt Regulator

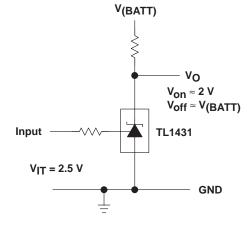
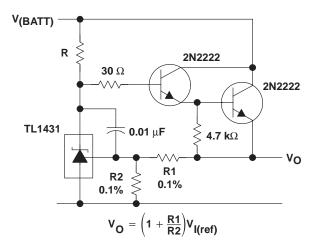


Figure 17. Single-Supply Comparator With Temperature-Compensated Threshold



NOTE A: R should provide cathode current \geq 1 mA to the TL1431 at minimum $V_{(BATT)}$.

Figure 18. Precision High-Current Series Regulator

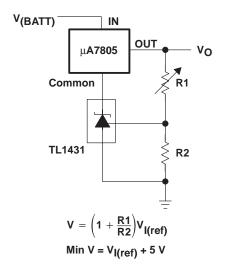


Figure 19. Output Control of a Three-Terminal Fixed Regulator

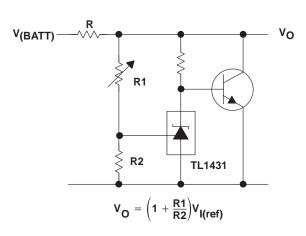
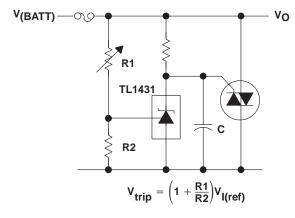
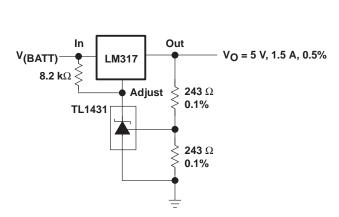


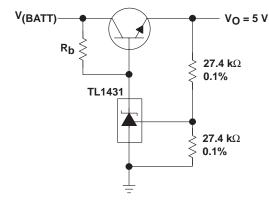
Figure 20. Higher-Current Shunt Regulator



NOTE A: Refer to the stability boundary conditions in Figure 15 to determine allowable values for C.

Figure 21. Crowbar





NOTE A: R_b should provide cathode current ≥ 1 mA to the TL1431.

Figure 22. Precision 5-V, 1.5-A, 0.5% Regulator

Figure 23. 5-V Precision Regulator

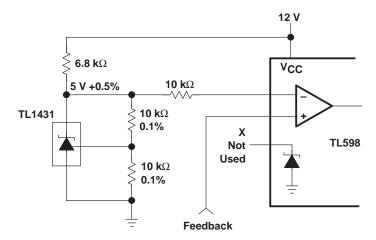
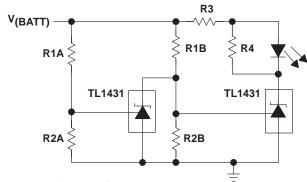


Figure 24. PWM Converter With 0.5% Reference



$$\begin{aligned} &\text{Low Limit} = \left(1 + \frac{R1B}{R2B}\right) V_{\text{I(ref)}} & & \\ &\text{High Limit} = \left(1 + \frac{R1A}{R2A}\right) V_{\text{I(ref)}} & & \\ &\text{Low Limit} < V_{\text{(BATT)}} < \text{High Limit} \end{aligned}$$

NOTE A: Select R3 and R4 to provide the desired LED intensity and cathode current ≥1 mA to the TL1431.

Figure 25. Voltage Monitor

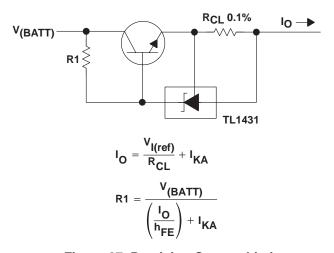


Figure 27. Precision Current Limiter

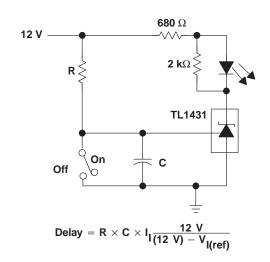


Figure 26. Delay Timer

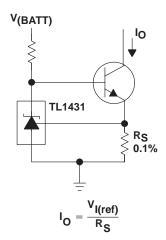


Figure 28. Precision Constant-Current Sink

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